

# Ultra-Small, Ultra-Low Power MEMS Oscillator

#### **Features**

- Wide Frequency Range: 3.5 kHz to 100 MHz
- Ultra-Low Power Consumption: 3 mA/1 μA (Active/Standby)
- · Ultra-Small Footprints
  - 1.6 mm × 1.2 mm
  - $2.0 \text{ mm} \times 1.6 \text{ mm}$
  - $2.5 \text{ mm} \times 2.0 \text{ mm}$
- Frequency Select Input Supports Two Pre-Defined Frequencies
- High Stability: ±20 ppm, ±25 ppm, ±50 ppm
- · Wide Temperature Range
  - Automotive: -40°C to +125°C
  - Ext. Industrial: -40°C to +105°C
  - Industrial: -40°C to +85°C
  - Ext. Commercial: -20° to +70°C
- Excellent Shock and Vibration Immunity
  - Qualified to MIL-STD-883
- · High Reliability
  - 20x Better MTF Than Quartz Oscillators
- Supply Range of 1.71V to 3.63V
- Short Sample Lead Time: <2 weeks
- · Lead Free & RoHS Compliant
- · Automotive Version Available: DSA61xxB

#### **Applications**

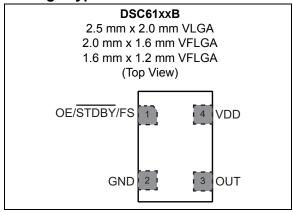
- Low Power/Portable Applications: IoT, Embedded/Smart Devices
- Consumer: Home Healthcare, Fitness Devices, Home Automation
- Industrial: Building/Factory Automation, Surveillance Camera
- Automotive (Please Refer to the DSA61xx Family)

#### **General Description**

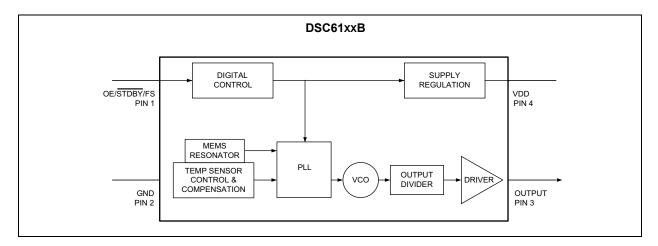
The DSC61xxB family of MEMS oscillators combines the industry leading low power consumption and ultra-small packages with exceptional frequency stability and jitter performance over temperature. The single-output DSC61xxB MEMS oscillators are excellent choices for use as clock references in small, battery-powered devices such as wearable and Internet of Things (IoT) devices in which small size, low power consumption, and long-term reliability are paramount.

The DSC61xxB family is available in ultra-small 1.6 mm x 1.2 mm, 2.0 mm x 1.6 mm, and 2.5 mm x 2.0 mm packages. These packages are "drop-in" replacements for standard 4-pin CMOS quartz crystal oscillators. The Automotive Grade AEC-Q100 qualified option is also available for this device.

#### Package Types



# **Block Diagram**



#### 1.0 ELECTRICAL CHARACTERISTICS

# **Absolute Maximum Ratings**

Supply Voltage	
Input Voltage (V <sub>IN</sub> )	
ESD Protection	4 KV HBM. 400V MM. 2 KV CDM

#### **ELECTRICAL CHARACTERISTICS**

<b>Electrical Characteristics:</b> Unless otherwise indicated, $V_{DD}$ = 1.8V –5% to 3.3V +10%, $T_A$ = –40°C to +125°C.							
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Supply Voltage	$V_{DD}$	1.71	_	3.63	V	Note 1	
Power Supply Ramp	t <sub>PU</sub>	0.1	_	100	ms	Note 8	
Active Supply Current	I <sub>DD</sub>	_	3.0	_	mA	f <sub>OUT</sub> = 27 MHz, V <sub>DD</sub> = 1.8V, No Load	
Chandley Cymaly Cymant	la-ray.	_	1			V <sub>DD</sub> = 1.8/2.5V, Note 2	
Standby Supply Current	I <sub>STBY</sub>	_	1.5	1	μA	V <sub>DD</sub> = 3.3V, Note 2	
Output Duty Cycle	SYM	45	_	55	%	_	
Frequency	$f_0$	0.0035	_	100	MHz	_	
Frequency Stability	Δf		_	±20 ±25 ±50	ppm	All temp ranges, Note 3	
Anina	۸.۴	_	_	±5		1st year @ 25°C	
Aging	Δf	_	_	±1	ppm	Per year after first year	
Startup Time	t <sub>SU</sub>	_	_	1.5	ms	From 90% V <sub>DD</sub> to valid clock output, T = 25°C	
la model a mia l'accela	V <sub>IH</sub>	0.7 x V <sub>DD</sub>	_	_	V	Input Logic High, Note 4	
Input Logic Levels	V <sub>IL</sub>	_	_	0.3 x V <sub>DD</sub>	V	Input Logic Low, Note 4	
Output Disable Time	t <sub>DA</sub>	_		200 + 2 Periods	ns	Note 5	
Output Enable Time	t <sub>EN</sub>			1	μs	Note 6	
Enable Pull-up Resistor	_	_	300		kΩ	If configured, Note 7	

- Note 1: Pin 4  $V_{DD}$  should be filtered with 0.1  $\mu F$  capacitor.
  - 2: Not including current through pull-up resistor on EN pin (if configured). Higher standby current seen at >3.3V V<sub>DD</sub>.
  - **3:** Includes frequency variations due to initial tolerance, temp. and power supply voltage.
  - 4: Input waveform must be monotonic with rise/fall time < 10 ms
  - **5:** Output Disable time takes up to two periods of the output waveform + 200 ns.
  - **6:** For parts configured with OE, not Standby.
  - **7:** Output is enabled if pad is floated or not connected.
  - 8: Time to reach 90% of target  $V_{DD}$ . Power ramp rise must be monotonic.

# **ELECTRICAL CHARACTERISTICS (CONTINUED)**

<b>Electrical Characteristics:</b> Unless otherwise indicated, $V_{DD} = 1.8V - 5\%$ to 3.3V +10%, $T_A = -40$ °C to +125°C.								
Parameters	Sym.	Min.	Тур.	Max.	Units	Co	nditions	
					.,	Output Logic Std. Drive	High, I = 3 mA,	
Output Lacia Lavala	V <sub>OH</sub>	0.8 X V <sub>DD</sub>	0.8 x V <sub>DD</sub> — V Output Logi High Drive			High, I = 6 mA,		
Output Logic Levels	V			0.0 V		Output Logic Std. Drive	Low, $I = -3 \text{ mA}$ ,	
	V <sub>OL</sub>	_		0.2 x V <sub>DD</sub>	V	Output Logic Low, I = -6 mA, High Drive		
Output Transition Time Rise Time/Fall Time		_	1	1.5	ns	DSC61x2 High Drive, 20% to 80% C <sub>L</sub> = 15 pF	V <sub>DD</sub> = 1.8V	
	t <sub>RX</sub> /t <sub>FX</sub>	_	0.5	1.0	ns		V <sub>DD</sub> = 2.5V/3.3V	
	t <sub>RY</sub> /t <sub>FY</sub>	_	1.2	2.0	ns	DSC61x1 Std Drive, 20% to 80% C <sub>L</sub> = 10 pF	V <sub>DD</sub> = 1.8V	
		_	0.6	1.2	ns		V <sub>DD</sub> = 2.5V/3.3V	
Dariad litter DMO		_	8.5	_		f <sub>OUT</sub> =	V <sub>DD</sub> = 1.8V	
Period Jitter, RMS	$J_{PER}$	_	7	_	ps <sub>RMS</sub>	27 MHz	V <sub>DD</sub> = 2.5V/3.3V	
Cycle-to-Cycle Jitter		_	50	70	ps	f <sub>OUT</sub> =	V <sub>DD</sub> = 1.8V	
(Peak)	J <sub>Cy–Cy</sub>	_	35	60		27 MHz	$V_{DD} = 2.5 V/3.3 V$	
Period Jitter		_	70	_		f <sub>OUT</sub> =	V <sub>DD</sub> = 1.8V	
(Peak-to-Peak)	$J_PP$	_	60	_	ps	27 MHz	$V_{DD} = 2.5 V/3.3 V$	

Note 1: Pin 4  $V_{DD}$  should be filtered with 0.1  $\mu F$  capacitor.

- 3: Includes frequency variations due to initial tolerance, temp. and power supply voltage.
- 4: Input waveform must be monotonic with rise/fall time < 10 ms
- **5:** Output Disable time takes up to two periods of the output waveform + 200 ns.
- **6:** For parts configured with OE, not Standby.
- 7: Output is enabled if pad is floated or not connected.
- 8: Time to reach 90% of target  $V_{DD}$ . Power ramp rise must be monotonic.

<sup>2:</sup> Not including current through pull-up resistor on EN pin (if configured). Higher standby current seen at  $>3.3V\ V_{DD}$ .

# **TEMPERATURE SPECIFICATIONS (Note 1)**

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Junction Operating Temperature	TJ	-40	_	+150	°C	_
Storage Ambient Temperature Range	T <sub>A</sub>	-55	_	+150	°C	_
Soldering Temperature	T <sub>S</sub>	_	+260	_	°C	40 sec. max.

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T<sub>A</sub>, T<sub>J</sub>, θ<sub>JA</sub>). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +150°C rating. Sustained junction temperatures above +150°C can impact the device reliability.

#### 2.0 PIN DESCRIPTIONS

The DSC61xxB is a highly configurable device and can be factory programmed in many different ways to meet the customer's needs. Microchip's ClockWorks<sup>®</sup> Configurator <a href="http://clockworks.microchip.com/Timing/">http://clockworks.microchip.com/Timing/</a> must be used to choose the necessary options, create the final part number, data sheet, and order samples. The descriptions of the pins are listed in Table 2-1.

TABLE 2-1: DSC61XXB PIN FUNCTION TABLE

Pin Number	Pin Name	Description
	OE	Output Enable: H = Active, L = Disabled (High Impedance).
(Note 1)	STDBY	Standby: H = Device is active, L = Device is in standby (Low Power Mode).
(Note 1)	FS	Frequency Select: H = Output Frequency 1, L = Output Frequency 2.
2	GND	Ground.
3	Output	Oscillator clock output.
4	VDD	Power supply: 1.71V to 3.63V.

**Note 1:** DSC610xB/1xB/3xB has a 300 kΩ internal pull-up resistor on pin 1. DSC614xB/5xB/7xB has no internal pull-up resistor on pin 1 and needs an external pull-up or to be driven by another chip.

An explanation of the different options listed in Table 2-1 follows.

#### 2.1 Pin 1

This is a control pin and may be configured to fulfill one of three different functions. If not actively driven, a 10 k $\Omega$  pull-up resistor is recommended.

#### 2.1.1 OUTPUT ENABLE (OE)

Pin 1 may be configured as OE. Oscillator output may be turned on and off according to the state of this pin.

#### 2.1.2 STDBY

Pin 1 may be configured as Standby. When the pin is low, both output buffer and PLL will be off and the device will enter a low power mode.

#### 2.1.3 FREQUENCY SELECT (FS)

Pin 1 may be configured as FS. The output may be set to one of two pre-programmed frequencies. The output clock frequencies can only be set to either kHz or MHz. A combination of kHz and MHz cannot be set.

#### 2.2 Pins 2 through 4

Pins 2 and 4 are the supply terminals, GND and VDD respectively. Pin 3 is the clock output, programmable to Standard and High Drive strength settings. Visit ClockWorks® Configurator to customize your device.

#### 2.3 Output Buffer Options

The DSC61xx family is available in multiple output driver configurations.

The standard-drive (61x1) and high-drive (61x2) deliver respective output currents of greater than 3 mA and 6 mA at 20%/80% of the supply voltage. For heavy loads of 15 pF or higher, the high-drive option is recommended.

# 3.0 DIAGRAMS

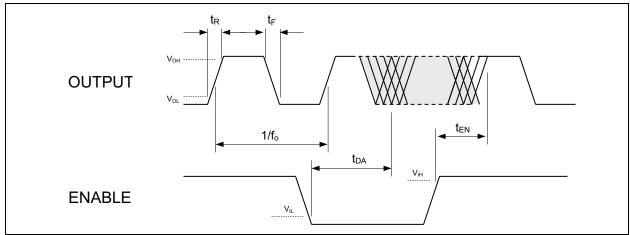


FIGURE 3-1: Output Waveform.

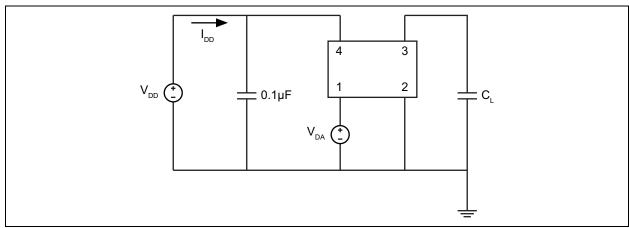


FIGURE 3-2: Test Circuit.

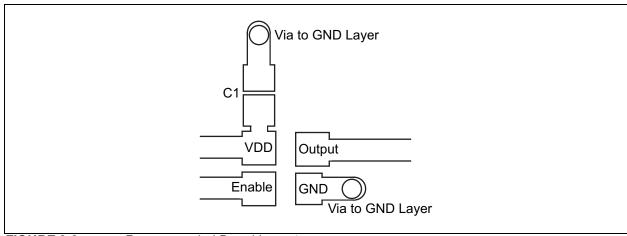


FIGURE 3-3: Recommended Board Layout.

# 4.0 SOLDER REFLOW PROFILE

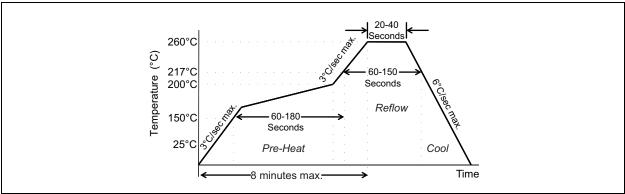
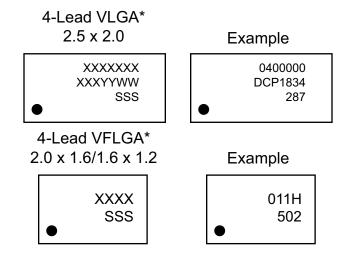


FIGURE 4-1: Solder Reflow Profile.

MSL 1 @ 260°C refer to JSTD-020C					
Ramp-Up Rate (200°C to Peak Temp)	3°C/sec. max.				
Preheat Time 150°C to 200°C	60 to 180 sec.				
Time maintained above 217°C	60 to 150 sec.				
Peak Temperature	255°C to 260°C				
Time within 5°C of actual Peak	20 to 40 sec.				
Ramp-Down Rate	6°C/sec. max.				
Time 25°C to Peak Temperature	8 minutes max.				

#### 5.0 PACKAGING INFORMATION

# 5.1 Package Marking Information



**Legend:** XX...X Product code or customer-specific information

Y Year code (last digit of calendar year)

YY Year code (last 2 digits of calendar year)

WW Week code (week of January 1 is week '01')

SSS Alphanumeric traceability code

e3 Pb-free JEDEC® designator for Matte Tin (Sn)

This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

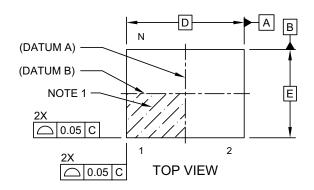
ullet, lacktriangle Pin one index is identified by a dot, delta up, or delta down (triangle mark).

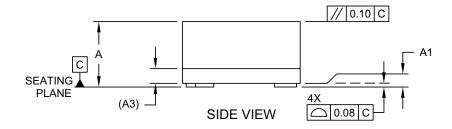
**Note**: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

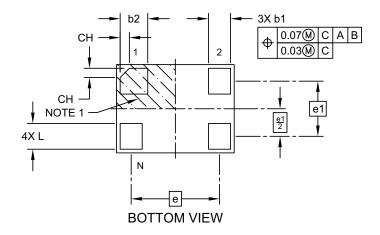
Underbar (\_) and/or Overbar (\_) symbol may not be to scale.

# 4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6x1.2 mm Body [VFLGA]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



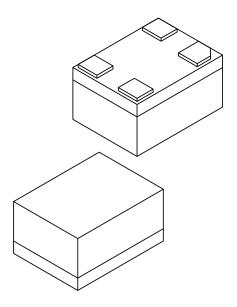




Microchip Technology Drawing C04-1199A Sheet 1 of 2

# 4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6x1.2 mm Body [VFLGA]

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS					
Dimension	MIN	NOM	MAX			
Number of Terminals	N		4			
Terminal Pitch	е		1.20 BSC			
Terminal Pitch	e1	0.75 BSC				
Overall Height	Α	0.79 0.84 0.89				
Standoff	A1	0.00	0.02	0.05		
Substrate Thickness (with Terminals)	A3	0.20 REF				
Overall Length	D		1.60 BSC			
Overall Width	E		1.20 BSC			
Terminal Width	b1	0.25	0.30	0.35		
Terminal Width	b2	0.325	0.375	0.425		
Terminal Length	L	0.30	0.35	0.40		
Terminal 1 Index Chamfer	СН	-	0.125	-		

#### Notes:

Note:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

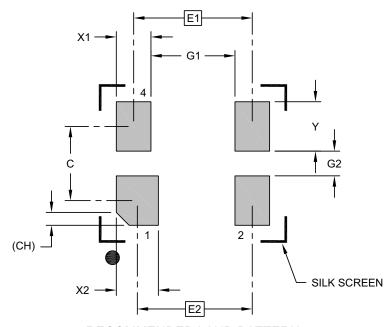
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1199A Sheet 2 of 2

# 4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6x1.2 mm Body [VFLGA]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX
Contact Pitch	E1		1.20 BSC	
Contact Pitch	E2		1.16 BSC	
Contact Spacing	С		0.75	
Contact Width (X3)	X1			0.35
Contact Width	X2			0.43
Contact Pad Length (X6)	Υ			0.50
Space Between Contacts (X4)	G1	0.85		
Space Between Contacts (X3)	G2	0.25		
Contact 1 Index Chamfer	CH	0.13 X 45° REF		

#### Notes:

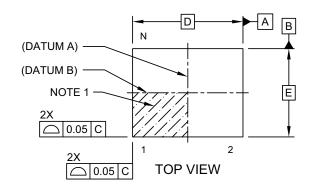
1. Dimensioning and tolerancing per ASME Y14.5M

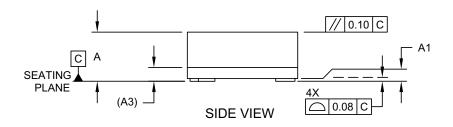
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

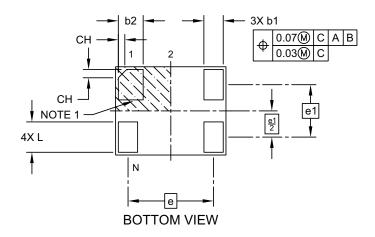
Microchip Technology Drawing C04-3199A

# 4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0x1.6 mm Body [VFLGA]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



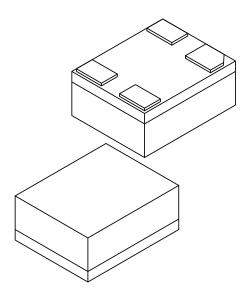




Microchip Technology Drawing C04-1200A Sheet 1 of 2

#### 4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0x1.6 mm Body [VFLGA]

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units MILLIMETERS							
	MILLIMETERS						
Dimension	MIN	NOM	MAX				
Number of Terminals	N		6				
Terminal Pitch	е		1.55 BSC				
Terminal Pitch	e1	0.95 BSC					
Overall Height	Α	0.79 0.84 0.89					
Standoff	A1	0.00	0.02	0.05			
Substrate Thickness (with Terminals)	A3		0.20 REF				
Overall Length	D		2.00 BSC				
Overall Width	E		1.60 BSC				
Terminal Width	b1	0.30	0.35	0.40			
Terminal Width	b2	0.40	0.45	0.50			
Terminal Length	L	0.50	0.55	0.60			
Terminal 1 Index Chamfer	CH	-	0.15	-			

#### Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

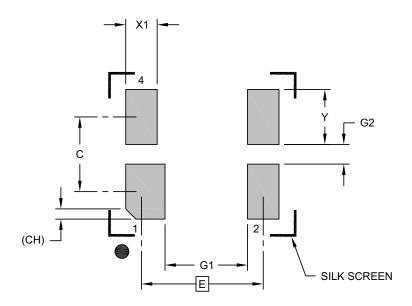
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1200A Sheet 2 of 2

# 4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0x1.6 mm Body [VFLGA]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	Е		1.55 BSC	
Contact Spacing	С		0.95	
Contact Width (X4)	X1			0.50
Contact Width (X2)	X2			0.40
Contact Pad Length (X6)	Υ			0.70
Space Between Contacts (X4)	G1	1.05		
Space Between Contacts (X3)	G2	0.25		·
Contact 1 Index Chamfer	CH	0.13 X 45° REF		

#### Notes:

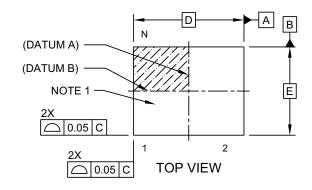
1. Dimensioning and tolerancing per ASME Y14.5M  $\,$ 

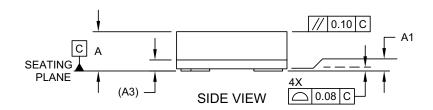
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

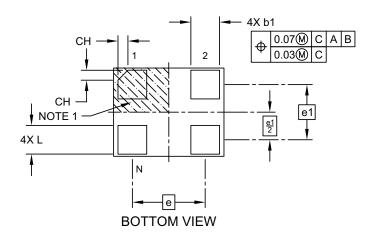
Microchip Technology Drawing C04-3200A

# 4-Lead Very Thin Land Grid Array (AUA) - 2.5x2.0 mm Body [VLGA]

**bte:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



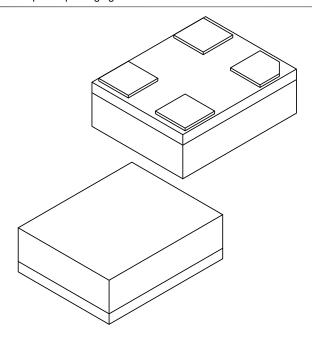




Microchip Technology Drawing C04-1202A Sheet 1 of 2

# 4-Lead Very Thin Land Grid Array (AUA) - 2.5x2.0 mm Body [VLGA]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension	Limits	MIN	NOM	MAX	
Number of Terminals	Ν		4		
Terminal Pitch	е		1.65 BSC		
Terminal Pitch	e1	1.25 BSC			
Overall Height	Α	0.79	0.84	0.89	
Standoff	A1	0.00	0.02	0.05	
Substrate Thickness (with Terminals)	A3		0.20 REF		
Overall Length	D		2.50 BSC		
Overall Width	E	2.00 BSC			
Terminal Width	b1	0.60	0.65	0.70	
Terminal Length	L	0.60	0.65	0.70	
Terminal 1 Index Chamfer	CH	-	0.225	-	

#### Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

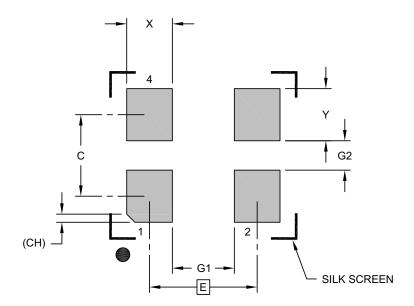
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1202A Sheet 2 of 2

# 4-Lead Very Thin Land Grid Array (AUA) - 2.5x2.0 mm Body [VLGA]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



**RECOMMENDED LAND PATTERN** 

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	Е	1.65 BSC		
Contact Spacing	С		1.25	
Contact Width (X4)	Х			0.70
Contact Pad Length (X6)	Υ			0.80
Space Between Contacts (X4)	G1	0.95		
Space Between Contacts (X3)	G2	0.45		
Contact 1 Index Chamfer	CH	0.13 X 45° REF		

#### Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-3202A

# **APPENDIX A: REVISION HISTORY**

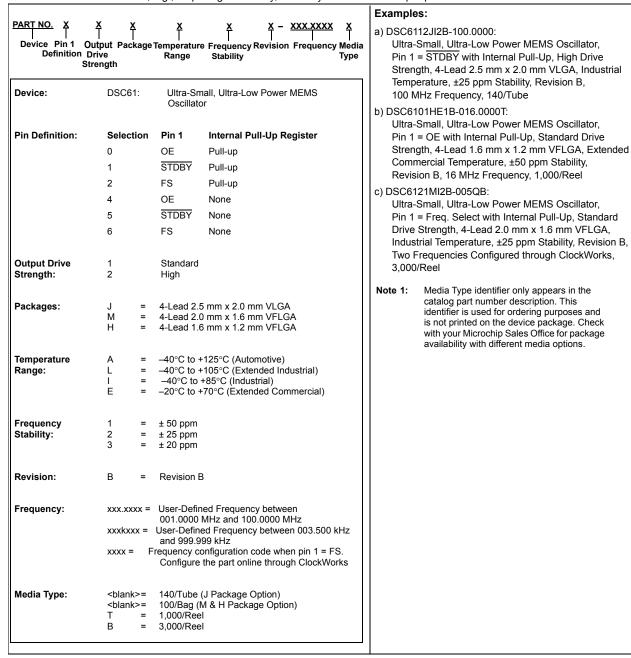
# Revision A (January 2019)

• Initial creation of DSC61xxB Microchip data sheet DS20006155A.

NOTES:

#### PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.



**Note 1:** Please visit Microchip ClockWorks<sup>®</sup> Configurator Website to configure the part number for customized frequency. http://clockworks.microchip.com/timing/.

NOTES:

#### Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
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